ET SEMIV.

21/11/2014 OP Code: 12422

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(3 Hours)

[Total Marks: 80

N.B.: (1) Question No. 1 is compulsory.

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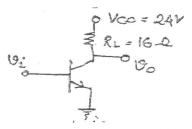
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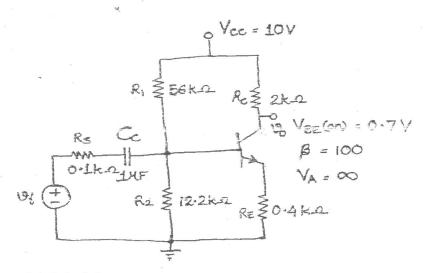
- (2) Solve any three questions from the remaining five.
- (3) Figures to the right indicate full marks.
- (3) Assume suitable data if required and mention the same in the answersheet.
- 1. Solve any five :-

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- (a) Draw the high frequency hybrid -pi equivalent circuit of a BJT and define the various components in the model.
- (b) Define differential and common mode gain, and differential and common mode input impedance of differential amplifiers.
- (c) Draw the circuit diagram and derive the relationship between the output current and reference current for Wilson current source.
- (d) Compare power BJTs and power MOSFETS. Determine the required power rating of a power BJT for the circuit given below.



- (e) List the characteristics of an ideal op-amp and compare with the practical ones.
- (f) With the help of a neat circuit diagram explain the working of transistorized series regulator.
- 2. (a) Determine the corner frequency and maximum gain of a bipolar common-emitter 10 circuit with an input coupling capacitor.

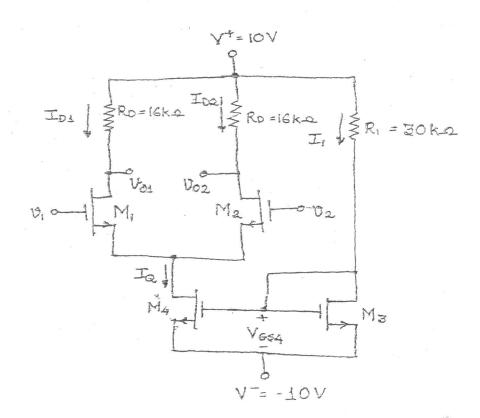


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- (b) Determine the unity-gain bandwidth of N-channel MOSFET with parameters K_n =0.25 mA/V², V_{TN} = 1V, λ =0, Cgd = 0.04pF, Cgs = 0.2 pF, V_{GS} = 3V. If a 10 k Ω load is connected to the output between drain and source determine the Miller capacitance and cut off frequency.
- 3. (a) Draw the small signal equivalent circuit of the bipolar differential amplifier. Determine its output voltage in the general form for one sided output $V_o = A_d$ $V_d + A_{cm} V_{cm}$, and hence the expressions for differential mode gain and common mode gain.
 - (b) For the MOSFET differential amplifier, the transistor parameters are $K_{n1} = K_{n2} = 0.1 \text{ mA/V}^2$, $K_{n3} = K_{n4} = 0.3 \text{ mA/V}^2$, $V_{TN} = 1 \text{V}$ for all transistors, $\lambda = 0.1 \text{ ma/V}^2$, $V_{TN} = 1 \text{V}$ for all transistors, $\lambda = 0.1 \text{ ma/V}^2$, $V_{TN} = 1 \text{V}$ for all transistors, $\lambda = 0.1 \text{ may}$ for M_1 , M_2 and M_3 and $\lambda = 0.01 \text{ V}^{-1}$ for M_4 . Determine the bias current I_Q , output resistance of current source, differential-mode voltage gain, common-mode voltage gain and CMRR for the differential amplifier.

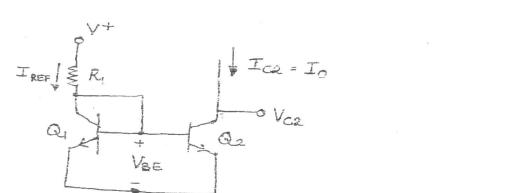


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4. (a) Determine I_{REF} and Io for the two transistor current source. The circuit parameters are V^+ =10V, V^- =0V, R_1 = 15 k Ω and transistor parameters are V_{BE} (on) = 0.7V, β =75, and V_A = ∞ .



- (b) Draw a neat diagram of a Widlar current source. Derive the relationship 8
- between the reference and bias currents.

 (c) Draw the circuit diagram and small signal equivalent circuit for a Darlington pair configuration. Derive the expression for its input resistance and overall current gain.
- Define slew rate. With the help of waveforms shown how slew rate affects the output response of an operational amplifier to a rectangular input voltage pulse. If the bias current of an op-amp is 19 μA and its internal frequency compensation capacitor has a value of 30 pF determine its slew rate.
 - (b) Draw the circuit diagram for a summing amplifier and determine the expression of output voltage v_0 in terms of the input voltages v_1 , v_2 and v_3 , and the resistances used in the circuit. If it is desired to have $v_0 = -(3v_1+4v_2+2v_3)$ find suitable values of these resistances.
 - (c) With the help of VI characteristics of a Zener diode explain the working of a Zener shunt regulator.
- (a) With the help of a neat diagram, dc and ac load lines explain the working of a transformer coupled class A amplifier. What is the effect of the transformer coupling on the power conversion efficiency of the class A amplifier.
 - (b) List the different techniques for biasing the class-AB power amplifier and explain any one them.
 - (c) Differentiate between two transistor and three transistor current sources.

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